

UV-Induced Degradation in N-Type Modules: Exploring Metastability and Recovery Pathways

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Kiwa PVEL

creating trust, driving progress

About Kiwa PVEL

- Independent lab for PV Module
 Performance and Reliability Testing.
- Headquarter test lab at Napa, US and a sister company at Suzhou, China.
- Developed PQP test sequences, updated every 2 years.
- Releases PV Module Scorecard every yr. 11th ed released on June 4, 2025.



Oral presentation: June 12 (Thurs), 1:45 pm

Understanding Solar Module Test Failures: Key Takeaways from Kiwa PVEL's PV Module Reliability Scorecard



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N-Type Modules and Growing UVID Concern

- Rapid growth of n-type silicon cell topologies (TOPCon, HJT, xBC, ...)
 - Higher efficiency due to better metallization scheme and improved passivation quality.
 - UV transparent encapsulants for current/ power gain.
- Marketed with improved first year (1%) and annual degradation rates (<0.4%).
 - Kiwa PVEL's testing shows resiliency to LID and LETID.
- Higher vulnerability to UV-induced degradation (UVID) due to increased cell sensitivity to UV radiation (280-360 nm).
 - Negative impact on energy yield, reliability and bankability.



Si- heterojunction (SHJ) $\Rightarrow \approx 8\%$ in 2024 $\Rightarrow \approx 12\%$ in 2035



Source: ITRPV 2025

Kiwa PVEL's UVID Testing

- Testing large-size industrial modules.
- UV Testing with front-side exposure.
- Exposure dose 120 kWh/m² of UV (280-400 nm) when using metal-halide lamps or 55 kWh/m² when using UV fluorescent lamps.
 - New UV chambers can accommodate 8 large-size modules (max. 2.7 m x 1.6 m), with turnaround time of 1 month.
- Equivalent to 1-2 years of outdoor exposure.
- Module temperature 60°C ± 5°C, under short-circuit condition.
- Characterization include visual inspection, front and rear I-V at STC, high & low-current EL, wet leakage current test.



UVID Sensitivity









UVID Test Results

- Largest "public" dataset:
 - Total 211 modules (~105 BOMs) evaluated.
 - 82% TOPCon modules.

N-type modules more susceptible to UVID.

- TOPCon and HJT modules showed a broad range of susceptibility (0.6% to 16.6%), indicating the variability in bill of materials, cell architecture, and process non-uniformities.
- More than 50% TOPCon showed power deg >5%.
- UVID-stable TOPCon BOMs are available.
- Some BOMs show quasi-stabilization after UVID60.
- Characteristic "Checkerboard" pattern in EL images.
 - Similar to PID or LETID sensitive modules.
 - Testing based on one-cell sample is not sufficient.





Degradation Pathways

- UVID mechanisms vary by cell types.
 - TOPCon BOMs show 0.6% to 16.6% deg, median 3.1%.
 - Voc most affected → cell anti-reflective coating or passivation degradation
 - Greater Isc & FF losses in few BOMs → mismatch loss
 - **HJT** BOMs show 1.5 to 6%, median 4.2% (limited samples).
 - Isc and FF losses are significant → front TCO/a-Si interface degradation
 - Voc is fairly stable
 - PERC BOMs show lower deg, median 2.2%.





-15.0

PERC

TOPCon

Technology

HJT

2.5

0.0

-2.5

-5.0

-7.5

-10.0

-12.5

-15.0

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Pmpp UVID120 Degradation (%)

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Field Degradation

- PQP's optional field exposed (FE) modules performance under MPP are evaluated after 1-year of deployment at Davis test site, CA.
- Total 50 BOMs. 2 test modules and 1 control per BOM.
- Significant degradation (median 2%, highest 8%) in fielded modules after 1 year of installation in Davis, CA.
 - Mainly due to UVID. Higher Voc loss and checkerboard pattern in test modules.
 - Control modules exhibited stable performance.
 - Combined LID and LETID Pmpp loss <1%.</p>



Control

n=50

Control

Control

n=50

Comparison Field and Lab Testing

- Like chamber test, TOPCon FE modules degraded dramatically after 1-year.
- Similar checkerboard patten in FE module.

Indoor chamber test

UVID is a real field-reliability problem.







TOPCon

Technology

Technology

Dark Degradation and Metastability Issues

- Signs of metastability observed in some UVID-stressed and field-exposed modules when stored in the dark.
 - Significant power loss and pronounced checkerboard pattern observed.
 - Degradation upto 1%/day in worst scenario.



Other's work





Thome et. al. Solar RRL (2024), 8, 2400628
 Gebhardt, P., Kräling, (2024), Prog Photovolt Res Appl.

Post-UVID Stabilization

- Dark storage (DS) degradation extent
 - PERC (minimal), HJT (moderate), TOPCon (extensive).
- Stabilization under full spectrum light soak (LS), partial recovery only
 - PERC No obvious degradation or recovery.
 - HJT Obvious recovery but at slower rate.
 - TOPCon Fast and effective recovery.

	Bad	Good	Bad	Good	Tier1	
Pmax	PERC	PERC	TOPCon	TOPCon	TOPCon	HJT
LID	0.0%	0.0%	0.4%	-0.1%	-0.1%	0.1%
UVID120	-3.0%	-1.9%	-5.6%	-1.4%	-4.4%	-4.5%
Dark Storage	-3.8%	-2.3%	-12.3%	-2.6%	-12.1%	-6.3%
LS 0.5kWh/m ²	-3.8%	-2.4%	-5.7%	-2.4%	-5.0%	-6.0%
LS 1kWh/m ²	-3.7%	-2.3%	-5.6%	-2.3%	-4.9%	-5.5%

	LID	UV120	DS 60d	LS 0.5	LS 1
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с).	TOPCon				
	HJT				
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Kiwa PVEL's New Stabilization Procedure

- Modules flashed within 48 h after test completion.
- If not, modules subjected to a full-spectrum light soak
 - Light source requirement:
 - Intensity over 500 W/m², indoors or outdoors.
 - Class CCC light source, at least 4% UVA (320-400 nm).
 - c-Si modules (PERC, TOPCon, HJT): At least 0.5 kWh/m² of light, total dose not to exceed 2 kWh/m².
 - CdTe modules: no light-soak requirement (different stabilization procedure).
 - Light soak under open-circuit.
- **Module flashed within 4 hours** after removing from light soaking.



UVID Mitigation at Cell Level

- First project tested in 2024 Q2, retest in 2024 Q4 with same BOM.
- From worse to best-in-class.
 - Original samples Pmpp degradation 6.5% (average), strong checkerboard pattern.
 - Retest samples degraded by only 1.4% (average), no EL defects.
- Cell design improvements (not disclosed by manufacturer)
 - Most likely due to front cell ARC/passivation layer process controls.
- Several other projects with similar excellent results after recent UVID retests





UVID Mitigation at Module Level

- Additives and UV cut-off wavelength are critical for UVID.
- Front encapsulant trends
 - EPE and POE are mainstream encapsulants.
 - EPE showing higher degradation.
 - Cut-off wavelength varies 220 to 380 nm.
 - Higher degradation below 350nm cut-off.
- UV down-conversion encapsulants are emerging.
 - UVID effects can be mitigated
 - Other reliability issues may trigger, need to be tested.



Key Takeaways

- UVID is a new **reliability concern for n-type** modules and observed in the field.
- UVID is likely driven by a combination of UVtransparent encapsulants and thinner antireflective coatings on cells.
- Front cell ARC/passivation layer process controls and better encapsulant additives selection can help in mitigating UVID.
- Recent UVID testing showed lesser modules are exceeding power loss >5%.
- TOPCon and HJT modules after UVID and field exposure exhibited dark storage degradation.
 - Full spectrum light soak (indoors or outdoors) stabilize the modules.



TOPCon BOMs





Funding provided by the Durable Module Materials Consortium 2 (DuraMAT 2), an Energy Materials Network Consortium funded by the U.S. Department of Energy, Office of Energy Efficiency and Renewable Energy, Solar Energy Technologies Office agreement number 38259. The views expressed in the article do not necessarily represent the views of the DOE or the U.S. Government.

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